L	Hits	Search Text	TDB	Time stems
Number	Hits	Search Text	DB	Time stamp
1	80	<pre>((((N ADJ1 type) near4 ((photo adj1 (sens\$3 or diode)) or sensor or diode)) same ((P ADJ1 type) near4</pre>	USPAT; US-PGPUB	2004/01/11 14:21
		transistor\$1)) and @ad<=19990826) and (cmos or mos of mosfet)		
2	1	("4258684").PN.	USPAT;	2004/01/11
3	1	("4528684").PN.	US-PGPUB USPAT;	11:17 2004/01/11
4	2	(("5781233") or ("5818052")).PN.	US-PGPUB USPAT;	11:53 2004/01/11
5	12	5818052.URPN.	US-PGPUB USPAT	12:01 2004/01/11
6	1	5818052.PN.	USPAT;	11:55 2004/01/11
7	1	"27" AND 5818052.PN.	US-PGPUB USPAT;	12:01 2004/01/11
8	1	"53" AND 5818052.PN.	US-PGPUB USPAT;	12:02 2004/01/11
9	1	(mos OR mosfet) AND 5818052.PN.	US-PGPUB USPAT;	12:03 2004/01/11
10	5730	guard with ring\$1	US-PGPUB USPAT;	12:04 2004/01/11
11	551	(P ADJ1 type) with (guard with ring\$1)	US-PGPUB USPAT;	12:05 2004/01/11
12	41066	(P ADJ1 type) with substrate\$1	US-PGPUB USPAT; US-PGPUB	12:05 2004/01/11 14:20
13	248	((P ADJ1 type) with (guard with ring\$1)) same ((P ADJ1 type) with	USPAT; US-PGPUB	2004/01/11
14	10416	substrate\$1)	USPAT;	2004/01/11
15	38	(((P ADJ1 type) with (guard with	US-PGPUB USPAT;	12:06 2004/01/11
16	24	ring\$1)) same ((P ADJ1 type) with substrate\$1)) same ((N ADJ1 type) near4 well\$1)	US-PGPUB	12:06
16	24	<pre>((((P ADJ1 type) with (guard with ring\$1)) same ((P ADJ1 type) with substrate\$1)) same ((N ADJ1 type) near4 well\$1)) and @ad<=19990826</pre>	USPAT; US-PGPUB	2004/01/11 14:24
17	34763	APS	USPAT; US-PGPUB	2004/01/11
18	14324	(P ADJ1 type) NEAR5 transistor	USPAT; US-PGPUB	2004/01/11
19	3401	(N adj1 type) near5 (diode or (photo adj1 diode))	USPAT; US-PGPUB	2004/01/11
20	716	<pre>((P ADJ1 type) NEAR5 transistor) and ((N adj1 type) near5 (diode or (photo adj1 diode)))</pre>	USPAT; US-PGPUB	2004/01/11
21	250		USPAT; US-PGPUB	2004/01/11
22	2	APS and (((P ADJ1 type) NEAR5 transistor) same ((N adj1 type) near5	USPAT; US-PGPUB	2004/01/11 14:22
23	160	((N adj1 type) near5 (diode or (photo	USPAT; US-PGPUB	2004/01/11 14:50
24	83	adj1 diode)))) and @ad<=19990826 (P ADJ1 type) NEAR5 reset near5 transistor	USPAT;	2004/01/11
25	3		US-PGPUB USPAT; US-PGPUB	14:45 2004/01/11 14:45
26	1	5757008.pn.	USPAT;	2004/01/11
27	41065	(P ADJ1 type) with substrate	US-PGPUB USPAT;	14:45 2004/01/11
28	1	5757008.pn. and ((P ADJ1 type) with substrate)	US-PGPUB USPAT;	14:45 2004/01/11
L	l	Substitute;	US-PGPUB	14:47

Search History 1/11/04 4:45:32 PM

_					
	29	305	schottky with ((N adj1 type) near5	USPAT;	2004/01/11
			(diode or (photo adjl diode)))	US-PGPUB	14:50
ı	30	1	((P ADJ1 type) with substrate) and	USPAT;	2004/01/11
ı	•	_	(5757008.pn. and ((P ADJ1 type) with	US-PGPUB	14:50
ı				US-PGPUB	14:50
			substrate))		i l
	31	994	((N adj1 type) near5 (diode or (photo	USPAT;	2004/01/11
			adj1 diode))) same ((P ADJ1 type) with	US-PGPUB	14:50
			substrate)		1
1	32	107		IICDAM -	2004/01/11
- [32	107	schottky and (((N adj1 type) near5	USPAT;	2004/01/11
			(diode or (photo adjl diode))) same ((P	US-PGPUB	14:50
1			ADJ1 type) with substrate))		
	33	77	(schottky and (((N adj1 type) near5	USPAT;	2004/01/11
1			(diode or (photo adj1 diode))) same ((P	US-PGPUB	15:45
			ADJ1 type) with substrate))) and	OS FGFOD	13.45
-					
-			@ad<=19990826		1
	34	17	imag\$3 and ((schottky and (((N adj1	USPAT;	2004/01/11
			type) near5 (diode or (photo adj1	US-PGPUB	15:11
			diode))) same ((P ADJ1 type) with	1	
-			substrate))) and @ad<=19990826)		
	2.5	_		l	0000400400
	35	0	mosfet and 5757008.pn.	USPAT;	2004/01/11
	,			US-PGPUB	15:16
	36	5476	column with (read adj1 out)	USPAT;	2004/01/11
1			, ,	US-PGPUB	15:16
	37	0	5757008.pn. and (column with (read adj1	USPAT;	2004/01/11
	<i>-</i> ,	ĺ		,	1
	20		out))	US-PGPUB	15:43
	38	1	(ground near5 voltage) and 5757008.pn.	USPAT;	2004/01/11
- ['				US-PGPUB	15:45
	39	79	(ground near5 voltage) same (guard with	USPAT;	2004/01/11
			ring\$1)	US-PGPUB	15:45
	40	16			
	40	46	((ground near5 voltage) same (guard	USPAT;	2004/01/11
			with ring\$1)) and @ad<=19990826	US-PGPUB	15:46
	41	1	((N adjl type) near5 (diode or (photo	USPAT;	2004/01/11
1			adj1 diode))) and (((ground near5	US-PGPUB	15:53
			voltage) same (guard with ring\$1)) and		
1			(gaara wren ringyr) and (gaara wren ringyr) and]
1	40	_			
1	42	0	((N adj1 type) near5 (diode or (photo	USPAT;	2004/01/11
1			adj1 diode))) same voltage same	US-PGPUB	15:53
			crosstalk		
ı	43	3	((N adj1 type) near5 (diode or (photo	USPAT;	2004/01/11
	•		adjl diode))) same crosstalk	US-PGPUB	16:44
1	44	7	(("5372955") or ("5757008") or	1	1
1	33	l '		USPAT;	2004/01/11
1			("5818052") or ("5881184") or	US-PGPUB	16:44
			("6049111") or ("6175383") or]	
			("6252218")).PN.		
-	_	2	"6362767"	USPAT;	2004/01/10
1		_		US-PGPUB	15:46
-	_		E202420 mm	1	1
	- .	1	5283428.pn.	USPAT;	2004/01/10
				US-PGPUB	15:26
	-	3	(("5953060") or ("5933190") or	USPAT;	2004/01/10
			("6011251")).PN.	US-PGPUB	18:09
	_	3193	(N ADJ1 type) near4 ((photo adj1	USPAT;	2004/01/11
			(sens\$3 or diode)) or sensor or diode)	US-PGPUB	12:06
	_	12051		1	
		13051	(P ADJ1 type) near4 transistor\$1	USPAT;	2004/01/11
				US-PGPUB	12:05
	-	195	((N ADJ1 type) near4 ((photo adj1	USPAT;	2004/01/10
			(sens\$3 or diode)) or sensor or diode))	US-PGPUB	18:12
1			same ((P ADJ1 type) near4 transistor\$1)		
	_	117		Henne-	2004/01/10
		11/	(((N ADJ1 type) near4 ((photo adj1	USPAT;	2004/01/10
	İ		(sens\$3 or diode)) or sensor or diode))	US-PGPUB	18:12
			same ((P ADJ1 type) near4		
			transistor(1)) and @ad<=19990826		
	<u>.</u>	416800	cmos or mos of mosfet	USPAT;	2004/01/10
		-10000			18:13
1	_	100	//N ADTI time) meand //mbata addi	US-PGPUB	
	-	186	((N ADJ1 type) near4 ((photo adj1	USPAT;	2004/01/10
			(sens\$3 or diode)) or sensor or diode))	US-PGPUB	18:13
			with (CMOS or MOS)		<u> </u>
		414	((P ADJ1 type) near4 transistor\$1) with	USPAT;	2004/01/10
			MOSFET	US-PGPUB	18:13
L			1	UN-FGFUB	1 10.13

-	0	(((N ADJ1 type) near4 ((photo adj1	USPAT;	2004/01/10
		(sens\$3 or diode)) or sensor or diode))	US-PGPUB	18:13
		with (CMOS or MOS)) same (((P ADJ1	1	
		type) near4 transistor\$1) with MOSFET)		
_	41065	(P ADJ1 type) with substrate	USPAT;	2004/01/10
			US-PGPUB	18:14
-	48			2004/01/11
		(sens\$3 or diode)) or sensor or diode))	US-PGPUB	11:17
1		same ((P ADJ1 type) near4		
		transistor\$1)) and @ad<=19990826) and		
		(cmos or mos of mosfet)) and ((P ADJ1		
		type) with substrate)		
-	9	imag\$3 and ((((((N ADJ1 type) near4	USPAT;	2004/01/10
		((photo adj1 (sens\$3 or diode)) or	US-PGPUB	18:32
		sensor or diode)) same ((P ADJ1 type)		
		near4 transistor\$1)) and @ad<=19990826)		
		and (cmos or mos of mosfet)) and ((P		
		ADJ1 type) with substrate))		